

December 2006



LP2985 Micropower 150 mA Low-Noise Ultra Low-Dropout Regulator in SOT-23 and micro SMD Packages Designed for Use with Very Low ESR Output Capacitors

General Description

The LP2985 is a 150 mA, fixed-output voltage regulator designed to provide ultra low-dropout and low noise in battery powered applications.

Using an optimized VIP[®] (Vertically Integrated PNP) process, the LP2985 delivers unequalled performance in all specifications critical to battery-powered designs:

Dropout Voltage: Typically 300 mV @ 150 mA load, and 7 mV @ 1 mA load.

Ground Pin Current: Typically 850 $\mu A @ 150$ mA load, and 75 $\mu A @ 1$ mA load.

Enhanced Stability: The LP2985 is stable with output capacitor ESR as low as $5 \text{ m}\Omega$, which allows the use of ceramic capacitors on the output.

Sleep Mode: Less than 1 μ A quiescent current when ON/OFF pin is pulled low.

Smallest Possible Size: SOT-23 and micro SMD packages use absolute minimum board space.

Precision Output: 1% tolerance output voltages available (A grade).

Low Noise: By adding a 10 nF bypass capacitor, output noise can be reduced to 30 μV (typical).

Multiple voltage options, from 2.5V to 5.0V, are available as standard products. Consult factory for custom voltages.

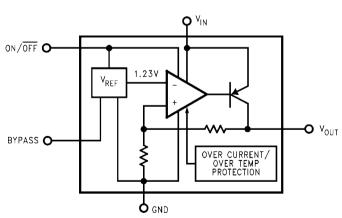
Features

- Ultra low dropout voltage
- Guaranteed 150 mA output current
- Smallest possible size (SOT-23, micro SMD package)
- Requires minimum external components
- Stable with low-ESR output capacitor
- <1 µA quiescent current when shut down</p>
- Low ground pin current at all loads
- Output voltage accuracy 1% (A Grade)
- High peak current capability
- Wide supply voltage range (16V max)
- Low Z_{OUT}: 0.3Ω typical (10 Hz to 1 MHz)
- Overtemperature/overcurrent protection
- -40°C to +125°C junction temperature range
- Custom voltages available

Applications

- Cellular Phone
- Palmtop/Laptop Computer
- Personal Digital Assistant (PDA)
- Camcorder, Personal Stereo, Camera

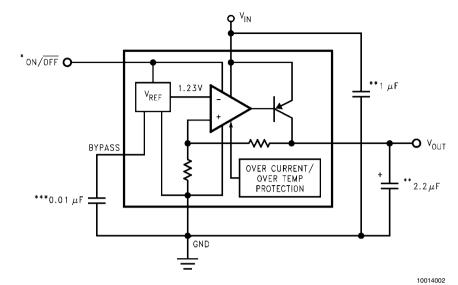
Block Diagram



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Basic Application Circuit

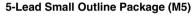


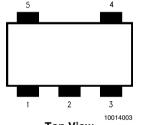
*ON/OFF input must be actively terminated. Tie to ${\rm V}_{\rm IN}$ if this function is not to be used.

**Minimum capacitance is shown to ensure stability (may be increased without limit). Ceramic capacitor required for output (see Application Hints).

***Reduces output noise (may be omitted if application is not noise critical). Use ceramic or film type with very low leakage current (see Application Hints).

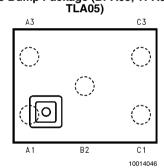
Connection Diagrams





Top View See NS Package Number MF05A For ordering information see *Table 1*

micro SMD, 5 Bump Package (BPA05, TPA05 & BLA05, &



Note: The actual physical placement of the package marking will vary from part to part. Package marking contains date code and lot traceability information, and will vary considerably. Package marking does not correlate to device type.

Top View See NS Package Number BPA05, TPA05, BLA05 & TLA05

Pin Descriptions

Name	Pin	Number	Function	
	SOT-23	micro SMD		
V _{IN}	1	C3	Input Voltage	
GND	2	A1	Common Ground (device substrate)	
ON/OFF	3	A3	Logic high enable input	
BYPASS	4	B2	Bypass capacitor for low noise operation	
V _{OUT}	5	C1	Regulated output voltage	

Output Voltage	Grade U Order Information Packade Warkind		Supplied as:		
(V) (V)- Lead Small Outli	na Daakara (5 5		
		er to LP2985LV datasheet.			
2.5	A	LP2985AIM5X-2.5	LAUA	3000 Units on Tape and Ree	
2.5	A	LP2985AIM5-2.5	LAUA	1000 Units on Tape and Ree	
2.5	STD	LP2985IM5X-2.5	LAUB	3000 Units on Tape and Ree	
2.5	STD	LP2985IM5-2.5	LAUB	1000 Units on Tape and Ree	
2.6	A	LP2985AIM5X-2.6	LCEA	3000 Units on Tape and Ree	
2.6	A	LP2985AIM5-2.6	LCEA	1000 Units on Tape and Ree	
2.6	STD	LP2985IM5X-2.6	LCEB	3000 Units on Tape and Ree	
2.6	STD	LP2985IM5-2.6	LCEB	1000 Units on Tape and Ree	
2.7	А	LP2985AIM5X-2.7	LALA	3000 Units on Tape and Ree	
2.7	А	LP2985AIM5-2.7	LALA	1000 Units on Tape and Ree	
2.7	STD	LP2985IM5X-2.7	LALB	3000 Units on Tape and Ree	
2.7	STD	LP2985IM5-2.7	LALB	1000 Units on Tape and Ree	
2.8	А	LP2985AIM5X-2.8	L0KA	3000 Units on Tape and Ree	
2.8	А	LP2985AIM5-2.8	L0KA	1000 Units on Tape and Ree	
2.8	STD	LP2985IM5X-2.8	L0KB	3000 Units on Tape and Ree	
2.8	STD	LP2985IM5-2.8	L0KB	1000 Units on Tape and Ree	
2.9	А	LP2985AIM5X-2.9	LAXA	3000 Units on Tape and Reel	
2.9	А	LP2985AIM5-2.9	LAXA	1000 Units on Tape and Reel	
2.9	STD	LP2985IM5X-2.9	LAXB	3000 Units on Tape and Reel	
2.9	STD	LP2985IM5-2.9	LAXB	1000 Units on Tape and Ree	
3.0	A	LP2985AIM5X-3.0	LOOA	· · · ·	
3.0	A	LP2985AIM5-3.0	LOOA	1000 Units on Tape and Ree	
3.0	STD	LP2985IM5X-3.0	LOOB	3000 Units on Tape and Ree	
3.0	STD	LP2985IM5-3.0	LOOB	1000 Units on Tape and Ree	
3.1	A	LP2985AIM5X-3.1	LOPA	3000 Units on Tape and Ree	
3.1	A	LP2985AIM5-3.1	LOPA	1000 Units on Tape and Ree	
3.1	STD	LP2985IM5X-3.1	LOPB	3000 Units on Tape and Ree	
3.1	STD	LP2985IM5-3.1	LOPB	1000 Units on Tape and Ree	
3.1			LOPB	3000 Units on Tape and Ree	
	A	LP2985AIM5X-3.2		· · · · · · · · · · · · · · · · · · ·	
3.2	A	LP2985AIM5-3.2	LOQA	1000 Units on Tape and Ree	
3.2	STD	LP2985IM5X-3.2	LOQB	3000 Units on Tape and Ree	
3.2	STD	LP2985IM5-3.2	LOQB	1000 Units on Tape and Ree	
3.3	A	LP2985AIM5X-3.3	LORA	3000 Units on Tape and Ree	
3.3	A	LP2985AIM5-3.3	LORA	1000 Units on Tape and Ree	
3.3	STD	LP2985IM5X-3.3	LORB	3000 Units on Tape and Ree	
3.3	STD	LP2985IM5-3.3	LORB	1000 Units on Tape and Ree	
3.5	А	LP2985AIM5X-3.5	LAIA	3000 Units on Tape and Ree	
3.5	А	LP2985AIM5-3.5	LAIA	1000 Units on Tape and Ree	
3.5	STD	LP2985IM5X-3.5	LAIB	3000 Units on Tape and Ree	
3.5	STD	LP2985IM5-3.5	LAIB	1000 Units on Tape and Ree	
3.6	А	LP2985AIM5X-3.6	LOSA	3000 Units on Tape and Ree	
3.6	А	LP2985AIM5-3.6	LOSA	1000 Units on Tape and Ree	
3.6	STD	LP2985IM5X-3.6	LOSB	3000 Units on Tape and Ree	
3.6	STD	LP2985IM5-3.6	LOSB	1000 Units on Tape and Ree	

Ordering Information

Output Voltage (V)	Grade	Order Information	Package Marking	Supplied as:
3.8	А	LP2985AIM5X-3.8	L0YA	3000 Units on Tape and Reel
3.8	А	LP2985AIM5-3.8	LOYA	1000 Units on Tape and Reel
3.8	STD	LP2985IM5X-3.8	L0YB	3000 Units on Tape and Reel
3.8	STD	LP2985IM5-3.8	L0YB	1000 Units on Tape and Reel
4.0	А	LP2985AIM5X-4.0	LOTA	3000 Units on Tape and Reel
4.0	А	LP2985AIM5-4.0	LOTA	1000 Units on Tape and Reel
4.0	STD	LP2985IM5X-4.0	LOTB	3000 Units on Tape and Reel
4.0	STD	LP2985IM5-4.0	LOTB	1000 Units on Tape and Reel
4.5	А	LP2985AIM5X-4.5	LA7A	3000 Units on Tape and Reel
4.5	А	LP2985AIM5-4.5	LA7A	1000 Units on Tape and Reel
4.5	STD	LP2985IM5X-4.5	LA7B	3000 Units on Tape and Reel
4.5	STD	LP2985IM5-4.5	LA7B	1000 Units on Tape and Reel
4.7	А	LP2985AIM5X-4.7	LAJA	3000 Units on Tape and Reel
4.7	А	LP2985AIM5-4.7	LAJA	1000 Units on Tape and Reel
4.7	STD	LP2985IM5X-4.7	LAJB	3000 Units on Tape and Reel
4.7	STD	LP2985IM5-4.7	LAJB	1000 Units on Tape and Reel
4.8	А	LP2985AIM5X-4.8	LAKA	3000 Units on Tape and Reel
4.8	A	LP2985AIM5-4.8	LAKA	1000 Units on Tape and Reel
4.8	STD	LP2985IM5X-4.8	LAKB	3000 Units on Tape and Reel
4.8	STD	LP2985IM5-4.8	LAKB	1000 Units on Tape and Reel
5.0	A	LP2985AIM5X-5.0	LOUA	3000 Units on Tape and Reel
5.0	A	LP2985AIM5-5.0	LOUA	1000 Units on Tape and Reel
5.0	STD	LP2985IM5X-5.0	LOUB	3000 Units on Tape and Reel
5.0	STD	LP2985IM5-5.0	LOUB	1000 Units on Tape and Reel
5.3	A	LP2985AIM5X-5.3	LFYA	3000 Units on Tape and Reel
5.3	A	LP2985AIM5-5.3	LFYA	1000 Units on Tape and Reel
5.3	STD	LP2985IM5X-5.3	LFYB	3000 Units on Tape and Reel
5.3	STD	LP2985IM5-5.3	LFYB	1000 Units on Tape and Reel
6.1	A	LP2985AIM5X-6.1	LF6A	3000 Units on Tape and Reel
6.1	A	LP2985AIM5-6.1	LF6A	1000 Units on Tape and Reel
6.1	STD	LP2985IM5X-6.1	LF6B	3000 Units on Tape and Reel
6.1	STD	LP2985IM5-6.1	LF6B	1000 Units on Tape and Reel
12	A	LP2985AIM5X-12	LH1A	3000 Units on Tape and Reel
(Note 11)	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~		Link	
12	A	LP2985AIM5-12	LH1A	1000 Units on Tape and Reel
(Note 11)				
12	STD	LP2985IM5X-12	LH1B	3000 Units on Tape and Reel
(Note 11)				
12	STD	LP2985IM5-12	LH1B	1000 Units on Tape and Reel
(Note 11)				
icro SMD, 5 Bum	p Package (E	3PA05 - 170 µm ball)		
2.4	А	LP2985AIBP-2.4		250 Units on Tape and Reel
2.4	А	LP2985AIBPX-2.4		3000 Units on Tape and Reel
2.4	STD	LP2985IBP-2.4		250 Units on Tape and Reel
2.4	STD	LP2985IBPX-2.4		3000 Units on Tape and Reel
2.5	А	LP2985AIBP-2.5		250 Units on Tape and Reel
2.5	А	LP2985AIBPX-2.5		3000 Units on Tape and Reel
2.5	STD	LP2985IBP-2.5		250 Units on Tape and Reel
2.5	STD	LP2985IBPX-2.5		3000 Units on Tape and Reel
2.6	А	LP2985AIBP-2.6		250 Units on Tape and Reel

Output Voltage (V)	Grade	Order Information	Package Marking	Supplied as:
2.6	A	LP2985AIBPX-2.6		3000 Units on Tape and Reel
2.6	STD	LP2985IBP-2.6		250 Units on Tape and Reel
2.6	STD	LP2985IBPX-2.6	3000 Units on Tape and Reel	
2.8	A	LP2985AIBP-2.8	250 Units on Tape and Reel	
2.8	А	LP2985AIBPX-2.8	3000 Units on Tape and Reel	
2.8	STD	LP2985IBP-2.8	250 Units on Tape and Reel	
2.8	STD	LP2985IBPX-2.8		3000 Units on Tape and Reel
2.9	А	LP2985AIBP-2.9		250 Units on Tape and Reel
2.9	А	LP2985AIBPX-2.9		3000 Units on Tape and Reel
2.9	STD	LP2985IBP-2.9		250 Units on Tape and Reel
2.9	STD	LP2985IBPX-2.9		3000 Units on Tape and Reel
3.0	А	LP2985AIBP-3.0		250 Units on Tape and Reel
3.0	А	LP2985AIBPX-3.0		3000 Units on Tape and Reel
3.0	STD	LP2985IBP-3.0		250 Units on Tape and Reel
3.0	STD	LP2985IBPX-3.0		3000 Units on Tape and Reel
3.3	А	LP2985AIBP-3.3		250 Units on Tape and Reel
3.3	A	LP2985AIBPX-3.3		3000 Units on Tape and Reel
3.3	STD	LP2985IBP-3.3		250 Units on Tape and Reel
3.3	STD	LP2985IBPX-3.3		3000 Units on Tape and Reel
3.6	А	LP2985AIBP-3.6		250 Units on Tape and Reel
3.6	Α	LP2985AIBPX-3.6		3000 Units on Tape and Reel
3.6	STD	LP2985IBP-3.6		250 Units on Tape and Reel
3.6	STD	LP2985IBPX-3.6		3000 Units on Tape and Reel
4.0	A	LP2985AIBP-4.0		250 Units on Tape and Reel
4.0	A	LP2985AIBPX-4.0		3000 Units on Tape and Reel
4.0	STD	LP2985IBP-4.0		250 Units on Tape and Reel
4.0	STD	LP2985IBPX-4.0		3000 Units on Tape and Reel
5.0	A	LP2985AIBP-5.0		250 Units on Tape and Reel
5.0	A	LP2985AIBPX-5.0		3000 Units on Tape and Reel
5.0	STD	LP2985IBP-5.0		250 Units on Tape and Reel
5.0	STD	LP2985IBPX-5.0		3000 Units on Tape and Reel
I		'PA05 - 170 μm ball)		
2.5	A	LP2985AITP-2.5		250 Units on Tape and Reel
2.5	A	LP2985AITPX-2.5		3000 Units on Tape and Reel
2.5	STD	LP2985ITP-2.5		250 Units on Tape and Reel
2.5	STD	LP2985ITPX-2.5		3000 Units on Tape and Reel
2.6	A	LP2985AITP-2.6		250 Units on Tape and Reel
2.6	A	LP2985AITPX-2.6		3000 Units on Tape and Reel
2.6	STD	LP2985ITP-2.6		250 Units on Tape and Reel
2.6	STD	LP2985ITPX-2.6		3000 Units on Tape and Reel
2.7	A	LP2985AITP-2.7		250 Units on Tape and Reel
2.7	A	LP2985AITPX-2.7		3000 Units on Tape and Reel
2.7	STD	LP2985ITP-2.7		250 Units on Tape and Reel
2.7	STD	LP2985ITPX-2.7		3000 Units on Tape and Reel
2.8	A	LP2985AITP-2.8		250 Units on Tape and Reel
2.8	A	LP2985AITPX-2.8		3000 Units on Tape and Reel
2.8	STD	LP2985ITP-2.8		250 Units on Tape and Reel
2.8	STD	LP2985ITPX-2.8		3000 Units on Tape and Reel

Output Voltage (V)	Grade	Order Information	Package Marking	Supplied as:	
2.9	А	LP2985AITPX-2.9		3000 Units on Tape and Reel	
2.9	STD	LP2985ITP-2.9	250 Units on Tape and Reel		
2.9	STD	LP2985ITPX-2.9	3000 Units on Tape and Reel		
3.0	А	LP2985AITP-3.0	250 Units on Tape and Reel		
3.0	А	LP2985AITPX-3.0		3000 Units on Tape and Reel	
3.0	STD	LP2985ITP-3.0		250 Units on Tape and Reel	
3.0	STD	LP2985ITPX-3.0		3000 Units on Tape and Reel	
3.3	А	LP2985AITP-3.3		250 Units on Tape and Reel	
3.3	А	LP2985AITPX-3.3		3000 Units on Tape and Reel	
3.3	STD	LP2985ITP-3.3		250 Units on Tape and Reel	
3.3	STD	LP2985ITPX-3.3		3000 Units on Tape and Reel	
5.0	А	LP2985AITP-5.0		250 Units on Tape and Reel	
5.0	А	LP2985AITPX-5.0	3000 Units on Tape and Reel		
5.0	STD	LP2985ITP-5.0	250 Units on Tape and Reel		
5.0	STD	LP2985ITPX-5.0		3000 Units on Tape and Reel	
icro SMD, 5 Bum	p Package (E	3LA05 - 300 µm ball)	·	•	
2.85	А	LP2985AIBL-285	250 Units on Tape and Reel		
2.85	А	LP2985AIBLX-285	3000 Units on Tape and Ree		
2.85	STD	LP2985IBL-285	250 Units on Tape and Reel		
2.85	STD	LP2985IBLX-285	3000 Units on Tape and Reel		
3.0	А	LP2985AIBL-3.0	250 Units on Tape and Reel		
3.0	А	LP2985AIBLX-3.0		3000 Units on Tape and Reel	
3.0	STD	LP2985IBL-3.0		250 Units on Tape and Reel	
3.0	STD	LP2985IBLX-3.0		3000 Units on Tape and Reel	
3.3	А	LP2985AIBL-3.3		250 Units on Tape and Reel	
3.3	А	LP2985AIBLX-3.3		3000 Units on Tape and Reel	
3.3	STD	LP2985IBL-3.3		250 Units on Tape and Reel	
3.3	STD	LP2985IBLX-3.3		3000 Units on Tape and Reel	
icro SMD, 5 Bum	p Package (T	LA05 - 300 μm ball)			
3.3	А	LP2985AITL-3.3 NOPB		250 Units on Tape and Reel	
3.3	А	LP2985AITLX-3.3 NOPB		3000 Units on Tape and Reel	
3.3	STD	LP2985ITL-3.3 NOPB		250 Units on Tape and Reel	
3.3	STD	LP2985ITLX-3.3 NOPB		3000 Units on Tape and Reel	

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature Range	–65°C to +150°C
Operating Junction Temperature	
Range	–40°C to +125°C
Lead Temp. (Soldering, 5 sec.)	260°C
ESD Rating (Note 2)	2 kV

Power Dissipation (Note 3) Input Supply Voltage (Survival) Input Supply Voltage (Operating) Shutdown Input Voltage (Survival) Output Voltage (Survival, (Note 4)) I_{OUT} (Survival)

Input-Output Voltage (Survival, (Note 5)) Internally Limited -0.3V to +16V 2.5V to +16V -0.3V to +16V -0.3V to +9V Short Circuit Protected -0.3V to +16V LP2985

Electrical Characteristics (Note 10)

Limits in standard typeface are for $T_J = 25^{\circ}$ C. and limits in boldface type apply over the full operating temperature range. Unless
otherwise specified: $V_{IN} = V_O(NOM) + 1V$, $I_L = 1$ mA, $C_{IN} = 1$ μ F, $C_{OUT} = 4.7$ μ F, $V_{ON/OFF} = 2V$.

Cumbal	Deveryoter	Conditions	Turn		5AI-X.X		35I-X.X	Unite
Symbol	Parameter	Conditions	Тур		te 6)	(NO Min	te 6)	Units
A) /	Output Voltage	L _ 1 mA		Min -1.0	Max 1.0	-1.5	Max 1.5	
ΔV _O	Tolerance	$I_L = 1 \text{ mA}$		-1.5	1.5			4
		$1 \text{ mA} \leq \text{I}_{\text{L}} \leq 50 \text{ mA}$				-2.5	2.5	
				-2.5	2.5	-3.5	3.5	%V _{NOM}
		1 mA ≤ I _L ≤ 150 mA		-2.5	2.5	-3.0	3.0	
• > /				-3.5	3.5	-4.0	4.0	
ΔV_0	Output Voltage	$V_O(NOM)+1V \le V_{IN} \le 16V$	0.007		0.014		0.014	%/V
ΔV_{IN}	Line Regulation				0.032		0.032	
V _{IN} –V _O	Dropout Voltage	I _L = 0	1		3		3	
	(Note 7)				5		5	
		I _L = 1 mA	7		10		10	1
					15		15	mV
		I _L = 10 mA	40		60		60	
					90		90	
		I _L = 50 mA	120		150		150	
					225		225	
		I _L = 150 mA	280		350		350	
					575		575	
I _{GND}	Ground Pin Current (Note 11)	I _L = 0	65		95		95	
					125		125	
		I _L = 1 mA	75		110		110	
					170		170	
		I _L = 10 mA	120		220		220	1
					400		400	
		I _L = 50 mA	350		600		600	μA
					1000		1000	
		I _L = 150 mA	850		1500		1500	1
					2500		2500	
		V _{ON/OFF} < 0.3V	0.01		0.8		0.8	
		V _{ON/OFF} < 0.15V	0.05		2		2	
V _{ON/OFF}	ON/OFF Input Voltage	High = O/P ON	1.4	1.6		1.6		
5.40.1	(Note 8)	Low = O/P OFF	0.55		0.15		0.15	- V
I _{ON/OFF}	ON/OFF Input Current	V _{ON/OFF} = 0	0.01		-2		-2	
		$V_{ON/OFF} = 5V$	5		15		15	μA

Symbol	Parameter	Conditions	Тур	LP2985AI-X.X (Note 6)		LP2985I-X.X (Note 6)		Units	
				Min	Max	Min	Max	1	
e _n	Output Noise	BW = 300 Hz to 50 kHz,							
	Voltage (RMS)	C _{OUT} = 10 μF	30					μV	
		C _{BYPASS} = 10 nF							
ΔV_{OUT}	Ripple Rejection	f = 1 kHz, C _{BYPASS} = 10 nF							
$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$		C _{OUT} = 10 μF	45					dB	
I _O (SC)	Short Circuit Current	R _L = 0 (Steady State)	100						
		(Note 9)	400					mA	
I _O (PK)	Peak Output Current	$V_{OUT} \ge V_{o}(NOM) - 5\%$	350					mA	

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its rated operating conditions.

Note 2: The ESD rating of pins 3 and 4 for the SOT-23 package, or pins 5 and 2 for the micro SMD package, is 1 kV.

Note 3: The maximum allowable power dissipation is a function of the maximum junction temperature, $T_J(MAX)$, the junction-to-ambient thermal resistance, θ_{J-A} , and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using:

$$P(MAX) = \frac{T_J(MAX) - T_A}{\theta_{J-A}}$$

Where the value of θ_{J-A} for the SOT-23 package is 220°C/W in a typical PC board mounting and the micro SMD package is 225°C/W. Exceeding the maximum allowable dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown.

Note 4: For 12V option, output voltage survival: -0.3 to +16V. If used in a dual-supply system where the regulator load is returned to a negative supply, the LP2985 output must be diode-clamped to ground.

Note 5: The output PNP structure contains a diode between the V_{IN} to V_{OUT} terminals that is normally reverse-biased. Reversing the polarity from V_{IN} to V_{OUT} will turn on this diode.

Note 6: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate National's Average Outgoing Quality Level (AOQL).

Note 7: Dropout voltage is defined as the input to output differential at which the output voltage drops 100 mV below the value measured with a 1V differential. **Note 8:** The ON/OFF input must be properly driven to prevent possible misoperation. For details, refer to Application Hints.

Note 9: The LP2985 has foldback current limiting which allows a high peak current when $V_{OUT} > 0.5V$, and then reduces the maximum output current as V_{OUT} is forced to ground (see Typical Performance Characteristics curves).

Note 10: Exposing the micro SMD device to direct sunlight will cause misoperation. See Application Hints for additional information.

Note 11: For 12V option, add 50 µA to all ON state quiescent current values.

Typical Performance Characteristics Unless otherwise specified: $C_{IN} = 1\mu$ F, $C_{OUT} = 4.7\mu$ F, $V_{IN} = V_{OUT}$ (NOM) +1, $T_A = 25^{\circ}$ C, ON/OFF pin is tied to V_{IN} .

V_{OUT} vs Temperature 3.615 V_{IN} = 4.60V $C_{IN} = 1 \ \mu F$ 3.6 $C_{OUT} = 4.7 \ \mu F$ Load = 1 mA3.605 V_{OUT} (V) 3.6 3.595 3.59 3.585 -50 -25 0 25 50 75 100 125 150 Junction Temperature (°C) 10014008

Short-Circuit Current

 $|V_{\rm IN}| = 16V$ $V_{OUT} = 2.8V_{...}$C_{IN} = 1 μ F... -C_{OUT} = 4.7 μ F...

 $C_{\text{BYPASS}} = 0.01 \ \mu\text{F}$

10014010

700

600

500

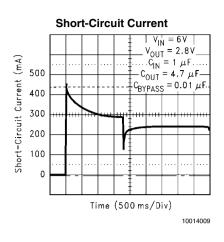
400

300

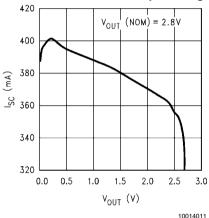
200 100

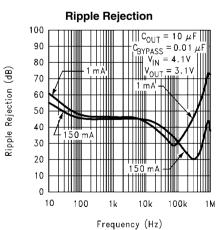
0

Short-Circuit Current (mA)



Short Circuit Current vs Output Voltage

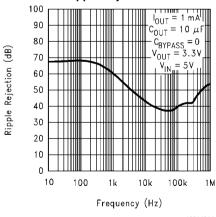




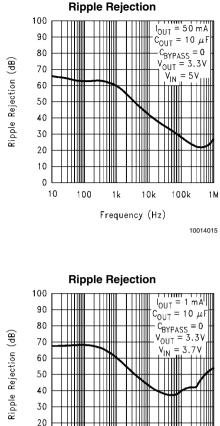
Time (100 ms/Div)

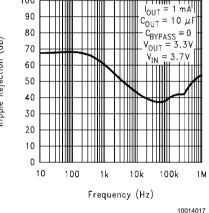
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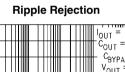
Ripple Rejection

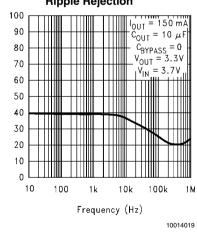


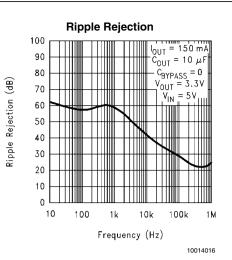
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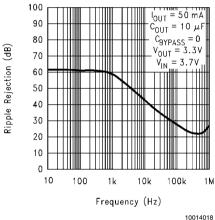


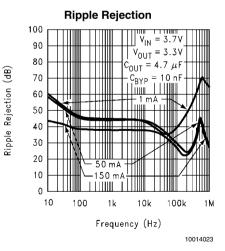




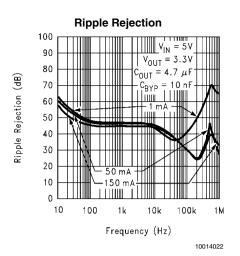




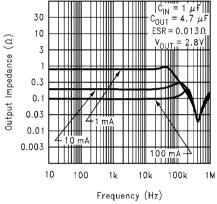




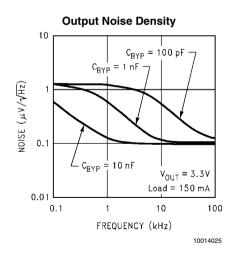
Ripple Rejection (dB)



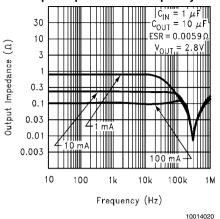


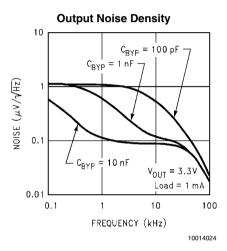


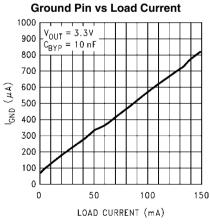
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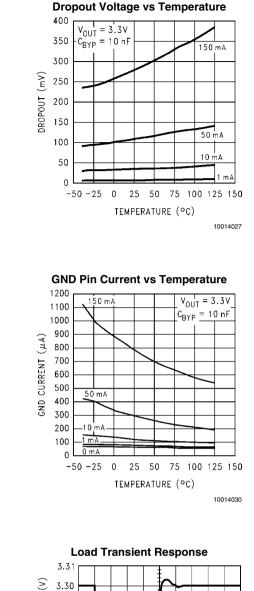
Output Impedance vs Frequency

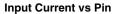


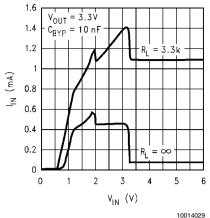




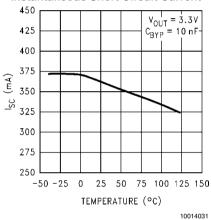
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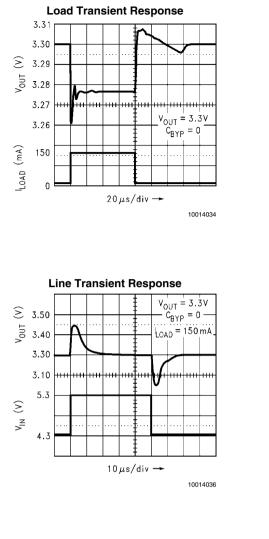


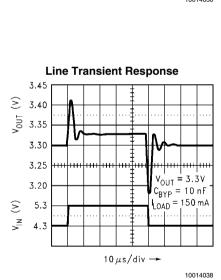


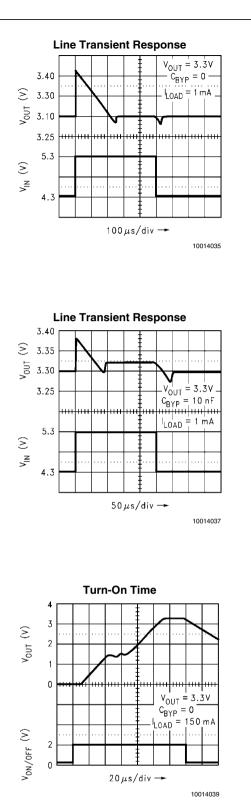
Instantaneous Short Circuit Current

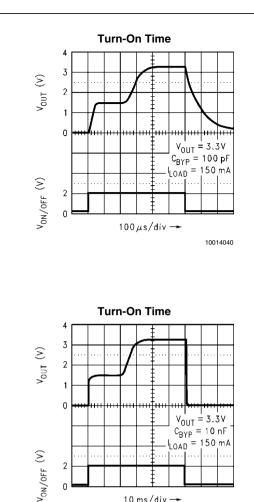


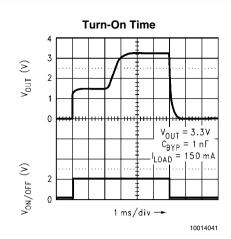
Load Transient Response 3.31 3.30 3.29 3.28 $V_{OUT} = 3.3V$ $V_{OUT} = 3.3V$ $C_{BYP} = 10 \text{ nF}$ $20 \mu \text{s/div} \rightarrow$ 10014033











Application Hints EXTERNAL CAPACITORS

Like any low-dropout regulator, the LP2985 requires external capacitors for regulator stability. These capacitors must be correctly selected for good performance.

10 ms/div -

10014042

Input Capacitor

An input capacitor whose capacitance is $\geq 1 \ \mu F$ is required between the LP2985 input and ground (the amount of capacitance may be increased without limit).

This capacitor must be located a distance of not more than 1 cm from the input pin and returned to a clean analog ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.

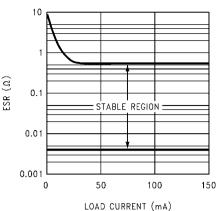
Important: Tantalum capacitors can suffer catastrophic failure due to surge current when connected to a low-impedance source of power (like a battery or very large capacitor). If a Tantalum capacitor is used at the input, it must be guaranteed by the manufacturer to have a surge current rating sufficient for the application.

There are no requirements for ESR on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitance will be \geq 1 µF over the entire operating temperature range.

Output Capacitor

The LP2985 is designed specifically to work with ceramic output capacitors, utilizing circuitry which allows the regulator to be stable across the entire range of output current with an output capacitor whose ESR is as low as 5 mΩ. It may also be possible to use Tantalum or film capacitors at the output, but these are not as attractive for reasons of size and cost (see next section Capacitor Characteristics).

The output capacitor must meet the requirement for minimum amount of capacitance and also have an ESR (equivalent series resistance) value which is within the stable range. Curves are provided which show the stable ESR range as a function of load current (see ESR graph below).



CONNERT (IIIA)

10014007

Important: The output capacitor must maintain its ESR within the stable region over the full operating temperature range of the application to assure stability.

The LP2985 requires a minimum of 2.2 μ F on the output (output capacitor size can be increased without limit).

It is important to remember that capacitor tolerance and variation with temperature must be taken into consideration when selecting an output capacitor so that the minimum required amount of output capacitance is provided over the full operating temperature range. It should be noted that ceramic capacitors can exhibit large changes in capacitance with temperature (see next section, *Capacitor Characteristics*).

The output capacitor must be located not more than 1 cm from the output pin and returned to a clean analog ground.

Noise Bypass Capacitor

Connecting a 10 nF capacitor to the Bypass pin significantly reduces noise on the regulator output. It should be noted that the capacitor is connected directly to a high-impedance circuit in the bandgap reference.

Because this circuit has only a few microamperes flowing in it, any significant loading on this node will cause a change in the regulated output voltage. For this reason, DC leakage current through the noise bypass capacitor must never exceed 100 nA, and should be kept as low as possible for best output voltage accuracy.

The types of capacitors best suited for the noise bypass capacitor are ceramic and film. High-quality ceramic capacitors with either NPO or COG dielectric typically have very low leakage. 10 nF polypropolene and polycarbonate film capacitors are available in small surface-mount packages and typically have extremely low leakage current.

CAPACITOR CHARACTERISTICS

The LP2985 was designed to work with ceramic capacitors on the output to take advantage of the benefits they offer: for capacitance values in the 2.2 μ F to 4.7 μ F range, ceramics are the least expensive and also have the lowest ESR values (which makes them best for eliminating high-frequency noise). The ESR of a typical 2.2 μ F ceramic capacitor is in the range of 10 m Ω to 20 m Ω , which easily meets the ESR limits required for stability by the LP2985.

One disadvantage of ceramic capacitors is that their capacitance can vary with temperature. Most large value ceramic capacitors ($\geq 2.2 \ \mu$ F) are manufactured with the Z5U or Y5V temperature characteristic, which results in the capacitance dropping by more than 50% as the temperature goes from 25° C to 85°C.

This could cause problems if a 2.2 μF capacitor were used on the output since it will drop down to approximately 1 μF at high ambient temperatures (which could cause the LM2985 to oscillate). If Z5U or Y5V capacitors are used on the output, a minimum capacitance value of 4.7 μF must be observed.

A better choice for temperature coefficient in ceramic capacitors is X7R, which holds the capacitance within $\pm 15\%$. Unfortunately, the larger values of capacitance are not offered by all manufacturers in the X7R dielectric.

Tantalum

Tantalum capacitors are less desirable than ceramics for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the 1 μ F to 4.7 μ F range.

Another important consideration is that Tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a Tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value.

It should also be noted that the ESR of a typical Tantalum will increase about 2:1 as the temperature goes from 25° C down to -40° C, so some guard band must be allowed.

On/Off Input Operation

The LP2985 is shut off by driving the ON/OFF input low, and turned on by pulling it high. If this feature is not to be used, the ON/OFF input should be tied to $V_{\rm IN}$ to keep the regulator output on at all times.

To assure proper operation, the signal source used to drive the ON/OFF input must be able to swing above and below the specified turn-on/turn-off voltage thresholds listed in the Electrical Characteristics section under V_{ON/OFF}. To prevent misoperation, the turn-on (and turn-off) voltage signals applied to the ON/OFF input must have a slew rate which is \geq 40 mV/µs.

Caution: the regulator output voltage can not be guaranteed if a slow-moving AC (or DC) signal is applied that is in the range between the specified turn-on and turn-off voltages listed under the electrical specification $V_{ON/OFF}$ (see Electrical Characteristics).

REVERSE INPUT-OUTPUT VOLTAGE

The PNP power transistor used as the pass element in the LP2985 has an inherent diode connected between the regulator output and input. During normal operation (where the input voltage is higher than the output) this diode is reversebiased.

However, if the output is pulled above the input, this diode will turn ON and current will flow into the regulator output. In such cases, a parasitic SCR can latch which will allow a high current to flow into $V_{\rm IN}$ (and out the ground pin), which can damage the part.

In any application where the output may be pulled above the input, an external Schottky diode must be connected from $V_{\rm IN}$ to $V_{\rm OUT}$ (cathode on $V_{\rm IN}$, anode on $V_{\rm OUT}$), to limit the reverse voltage across the LP2985 to 0.3V (see Absolute Maximum Ratings).

MICRO SMD MOUNTING

The micro SMD package requires specific mounting techniques which are detailed in National Semiconductor Application Note # 1112. Referring to the section *Surface Mount Technology (SMT) Assembly Considerations*, it should be noted that the pad style which must be used with the 5-pin package is the NSMD (non-solder mask defined) type.

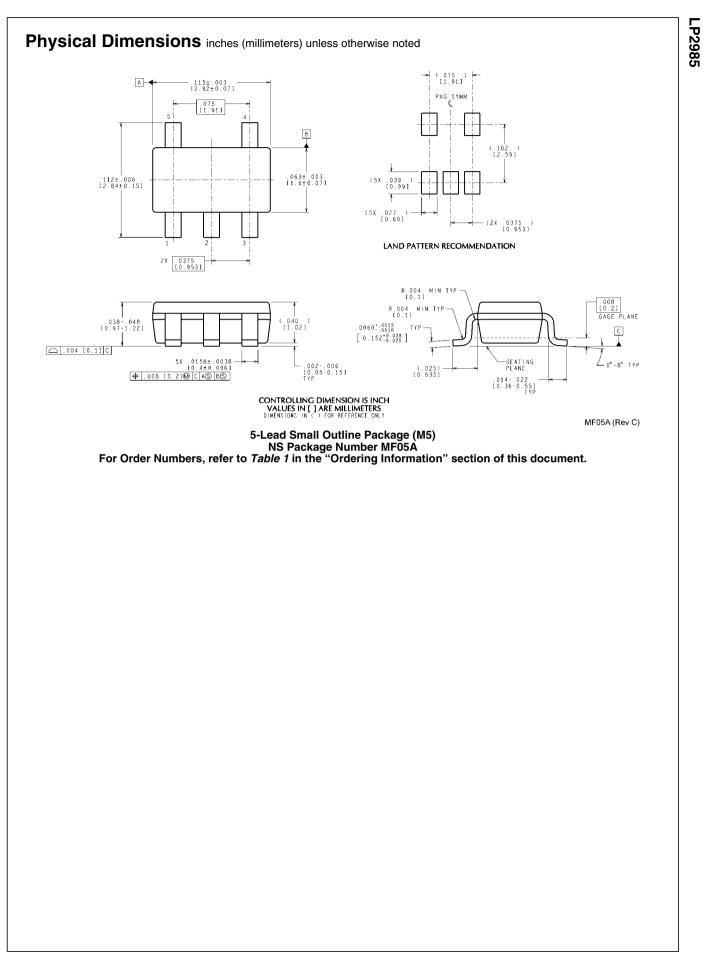
For best results during assembly, alignment ordinals on the PC board may be used to facilitate placement of the micro SMD device.

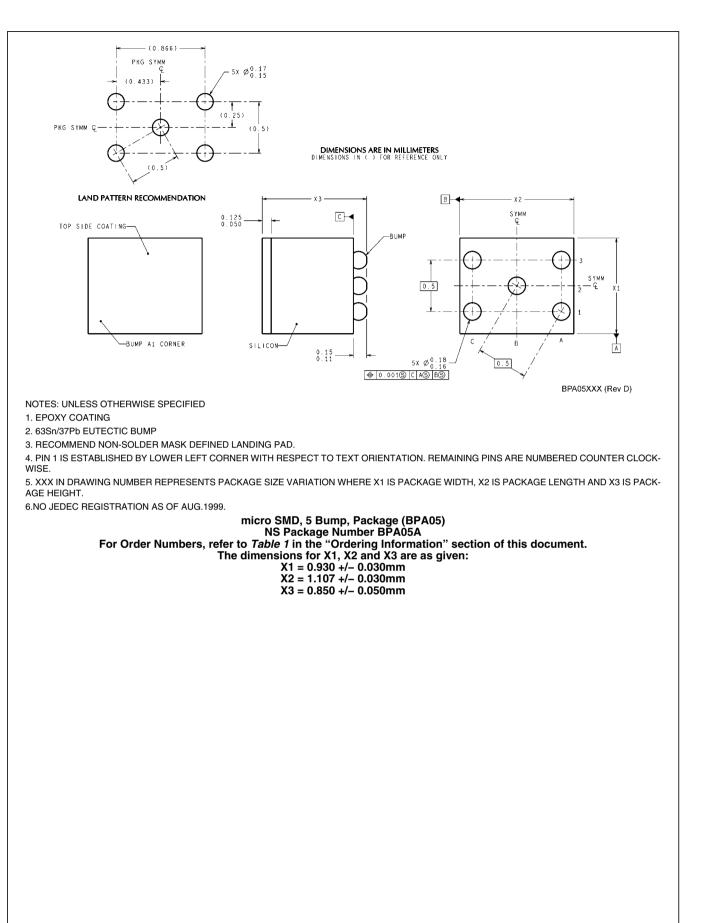
MICRO SMD LIGHT SENSITIVITY

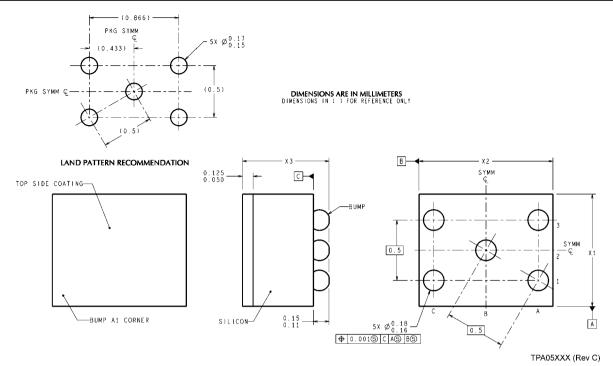
Exposing the micro SMD device to direct sunlight will cause misoperation of the device. Light sources such as Halogen

lamps can also affect electrical performance if brought near to the device.

The wavelenghts which have the most detrimental effect are reds and infra-reds, which means that the fluorescent lighting used inside most buildings has very little effect on performance. A micro SMD test board was brought to within 1 cm of a fluorescent desk lamp and the effect on the regulated output voltage was negligible, showing a deviation of less than 0.1% from nominal.







NOTES: UNLESS OTHERWISE SPECIFIED

1. EPOXY COATING

2. 63Sn/37Pb EUTECTIC BUMP

3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.

4. PIN 1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION. REMAINING PINS ARE NUMBERED COUNTER CLOCK-WISE.

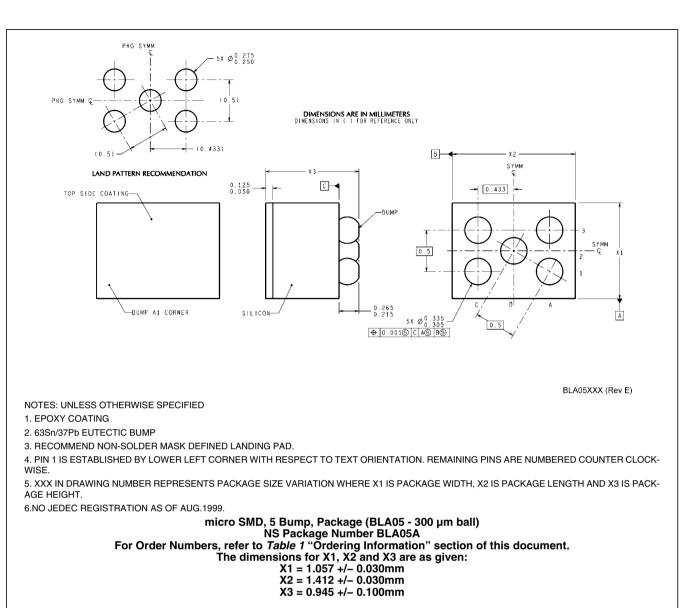
5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACK-AGE HEIGHT.

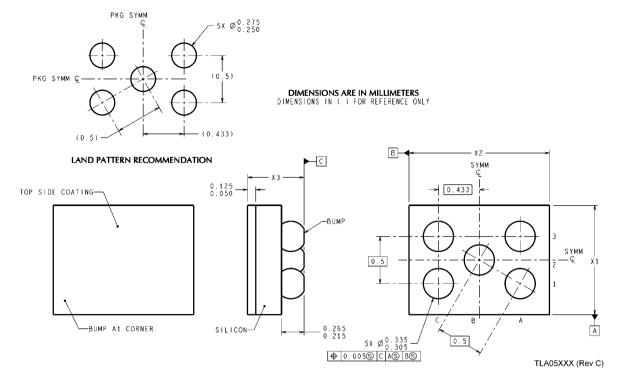
6.NO JEDEC REGISTRATION AS OF AUG.1999.

micro SMD, 5 Bump, Package (TPA05 - 170 μm ball) NS Package Number TPA05 For Order Numbers, refer to *Table 1* "Ordering Information" section of this document. The dimensions for X1, X2 and X3 are as given:

SIONS ION AN, AZ ANU AS AN
X1 = 0.930 +/- 0.030mm
X2 = 1.107 +/- 0.030mm
X3 = 0.500 +/- 0.075mm







NOTES: UNLESS OTHERWISE SPECIFIED

1. EPOXY COATING

2. 63Sn/37Pb EUTECTIC BUMP

3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.

4. PIN 1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION. REMAINING PINS ARE NUMBERED COUNTER CLOCK-WISE.

5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACK-AGE HEIGHT.

6.NO JEDEC REGISTRATION AS OF AUG.1999.

micro SMD, 5 Bump, Package (TLA05 - 300 µm ball) NS Package Number TLA05 For Order Numbers, refer to *Table 1* "Ordering Information" section of this document. The dimensions for X1, X2 and X3 are as given: X1 = 1.031 +/- 0.030mm X2 = 1.412 +/- 0.030mm X3 = 0.600 +/- 0.075mm

Notes

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